Low Power Bipolar Transistors

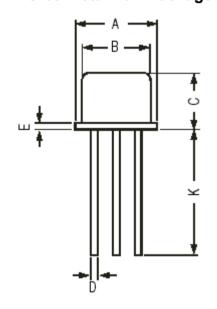




Features:

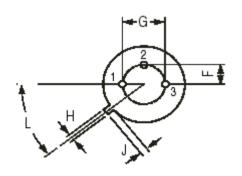
- PNP Silicon Planar switching Transistors.
- General Purpose Transistor.

TO-39 Metal Can Package



Dimensions	Minimum	Maximum
A	8.50	9.39
В	7.74	8.50
С	6.09	6.60
D	0.40	0.53
E	-	0.88
F	2.41	2.66
G	4.82	5.33
Н	0.71	0.86
J	0.73	1.02
K	12.70	-
L	42°	48°

Dimensions : Millimetres





Pin Configuration

- 1. Emitter
- 2. Base
- 3. Collector

multicomp

Page 1 07/04/06 V1.0





Absolute Maximum Ratings

Description	Symbol	Value	Unit	
Collector Emitter Voltage	V _{CEO}	40		
Collector Base Voltage	V _{CBO}	60	V	
Emitter Base Voltage	V _{EBO}	5		
Collector Current Continuous	I _C	600	mA	
Power Dissipation at T _a = 25°C Derate Above 25°C	D	600 3.43	mW mW/°C	
Power Dissipation at T _C = 25°C Derate Above 25°C	P _D	3.0 17.2	W mW/°C	
Operating and Storage Junction Temperature Range	T _j , T _{stg}	-65 to +200	°C	

Electrical Characteristics (T_a = 25°C unless specified otherwise)

Description	Symbol	Test Condition	Minimum	Maximum	Unit	
Collector Emitter Voltage	*V _{CEO}	I _C = 10mA, I _B = 0	40	-		
Collector Base Voltage	V _{CBO}	$I_{C} = 10\mu A, I_{E} = 0$	60	-	V	
Emmiter Base Voltage	V _{EBO}	$I_E = 10\mu A, I_C = 0$	5	-		
Collector Cut off Current	I _{CEX}	$V_{CE} = 30V, V_{BE} = 0.5V$	-	50	nA	
Collector Cut off Current		V _{CB} = 50V, I _E = 0	-	- 20	nA	
	Ісво	$V_{CB} = 50V, I_{E} = 0,$ $T_{a} = 150^{\circ}C$	-		μΑ	
Base Current	I _B	V _{CE} = 30V, V _{BE} = 0.5V	-	50	nA	
DC Current Gain	h _{FE}	I_{C} = 0.1mA, V_{CE} = 10V I_{C} = 1mA, V_{CE} = 10V I_{C} = 10mA, V_{CE} = 10V * I_{C} = 150mA, V_{CE} = 10V * I_{C} = 500mA, V_{CE} = 10V	-	>35 >50 >75 100 - 300 >30	-	
Small Signal Characteristics						
Collector Emitter Saturation Voltage	*V _{CE (sat)}	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$ $I_C = 500 \text{mA}, I_B = 50 \text{mA}$	-	0.4 1.6		
Base Emitter Saturation Voltage	*V _{BE (sat)}	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$ $I_C = 500 \text{mA}, I_B = 50 \text{mA}$	-	1.3 2.6	V	
Transition Frequency	**f _T	I_C = 50mA, V_{CE} = 20V f = 100MHz	200	-	MHz	
Output Capacitance	C _{obo}	$V_{CB} = 10V, I_{E} = 0$ f = 100KHz	-	8.0	pF	
Input Capacitance	C _{ibo}	$V_{BE} = 2V, I_{C} = 0$ f = 100KHz	-	30		

^{*}Pulse Test: Pulse Width ≤300μs, Duty Cycle ≤2%.

^{**}f_T is defined as the frequency at which /h_{FE}/ extrapolates to unity.



Page 2 07/04/06 V1.0





Electrical Characteristics ($T_a = 25$ °C unless specified otherwise)

Description	Symbol	Test Condition	Minimum	Maximum	Unit
Switching Time					
Delay Time	t _d		-	10	
Rise Time	t _r	I _C = 150mA, I _{B1} = 15mA, V _{CC} = 30V	-	40	
Turn on Time	t _{on}		-	45	20
Storage Time	t _S		-	80	nS nS
Fall Time	t _f	$I_C = 150 \text{mA}, I_{B1} = I_{B2} = 15 \text{mA},$ $V_{CC} = 6 \text{V}$	-	30	
Turn off Time	t _{off}		-	100	

Part Number Table

Package	Part Number
TO-39	2N2905

Low Power Bipolar Transistors



Notes:

International Sales Offices:



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07/04/06 V1.0 Page 4